

GaAs MMIC Limiter Chip, 4-8GHz

Performance characteristics

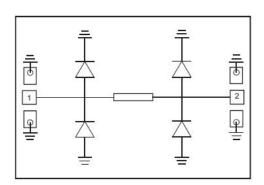
Frequency range: 4 - 8 GHz
 Insertion loss: 0.5 dB (Typ.)
 Clipping level: 16dBm

Power handling: 42dBm (CW)

50Ohm input / output100% on-wafer testing

• Chip size: 1.92 x 1.02 x 0.1mm

Functional Block Diagram



Product Introduction

GLM-0408B is a GaAs MMIC limiter with a frequency range of $4\sim8 \, \text{GHz}$, 50Ω input/output, 0.5dB within the operating frequency band, 1.3 input and output standing wave, and 42dBm burnout resistance. The chip is small in size and does not integrate input DC blocking capacitors on the chip. The chip uses on-chip through-hole metallization technology to ensure good grounding, does not require additional grounding measures, and is simple and convenient to use. The back of the chip is metallized and is suitable for eutectic sintering or conductive adhesive bonding processes.

Use restriction parameter ¹		
Maximum input power	+42dBm	
Operating temperature	-55 ~ + 125 °C	
Storage temperature	-65 ~ +150°C	

[1] Exceeding any of these maximum limits may cause permanent damage.

Electrical performance parameters (TA = +25°C)					
Index	Minimum	Typical Value	Maximum	Unit	
Frequency Range	4-8			GHz	
Insertion loss	-	0.5	0.6	dB	
Input return loss	17	18		dB	
Output return loss	18	20		dB	
Clipping level	-	17	-	dBm	
Anti-burning power		42		dBm	

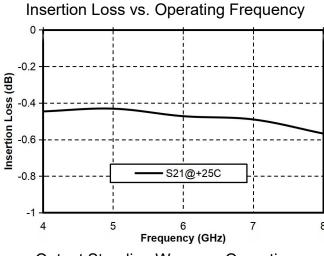
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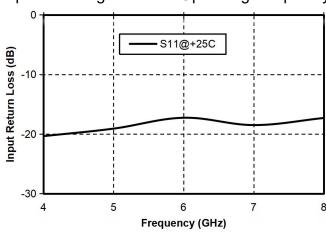


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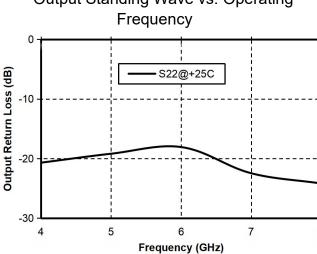
Main index test curve



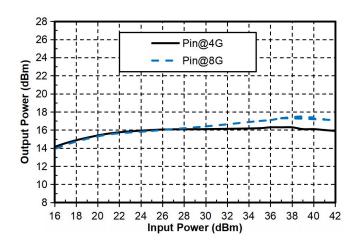
Input Standing Wave vs. Operating Frequency



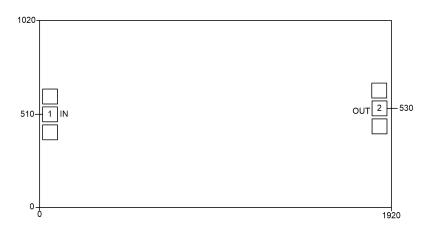
Output Standing Wave vs. Operating



Clipping Level @4G & @8G



Appearance structure ²



[2] All units in the figure are micrometers



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Recommended assembly drawing



Bonding point definition			
Bonding point	Function	Functional Description	
number	Symbol		
		RF signal input terminal . The chip input terminal does not	
1 RF IN	RF IN	integrate a DC blocking capacitor. It is recommended to connect	
		an external DC blocking capacitor.	
2	RF OUTPUT	RF signal output terminal , the chip output terminal has integrated	
		DC blocking capacitor	
Chip bottom	GND	The bottom of the chip needs to be well grounded to RF and DC	

Precautions for use

- The chip needs to be stored in an anti-static container and kept in a nitrogen environment.
- Do not attempt to clean the bare die surface using wet chemical methods.
- Please strictly comply with ESD protection requirements to avoid electrostatic damage to bare chips.
- General operation: Please use precision pointed tweezers to pick up bare chips. Avoid touching the chip surface with tools or fingers during operation.
- Rack mounting operation suggestions: Bare chip mounting can be done by AuSn solder eutectic sintering or conductive adhesive bonding. The mounting surface must be clean and flat.
- Sintering process: It is recommended to use AuSn solder sheets with a gold-tin ratio of 80/20. The working surface temperature reaches 255 °C and the tool (vacuum chuck) temperature reaches 265 °C. When the high-temperature mixed gas (nitrogen-hydrogen ratio of 90/10) is blown to the chip, the temperature at the top of the tool should be raised to 290 °C. Do not let the chip exceed 320 °C for more than 20 seconds. The friction time should not exceed 3 seconds.
- Bonding process: The amount of conductive glue dispensed should be as small as possible. After
 the chip is placed in the installation position, the conductive glue should be vaguely visible around
 it. For curing conditions, please follow the information provided by the conductive glue

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manufacturer.

Bonding operation suggestions: Use Φ0.025mm (1mil) gold wire for both ball and wedge bonding. Thermo-ultrasonic bonding temperature is 150 °C. The pressure of the wedge for ball bonding is 40~50gf, and the pressure of the wedge bonding is 18~22gf. Use the smallest possible ultrasonic energy. The bonding starts at the pressure point on the chip and ends at the package (or substrate) .

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